

Pb Free Plating Product

F60UP60DN

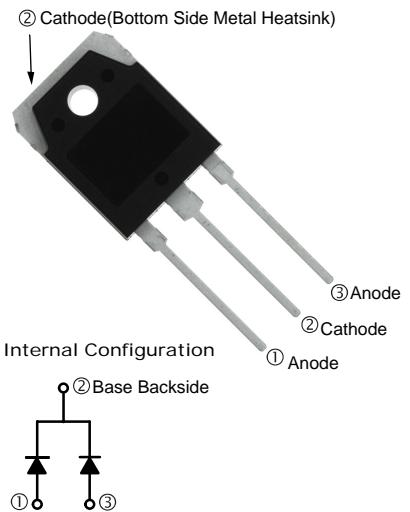


60Amperes,600Volts Heatsink Common Cathode Ultra Fast Recovery Rectifiers

APPLICATION

- Freewheeling, Snubber, Clamp
- Inversion Welder
- PFC
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- UPS

TO-3PB(TO-3PN)

**PRODUCT FEATURE**

- Ultrafast Recovery Time
- Soft Recovery Characteristics
- Low Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Leakage Current

GENERAL DESCRIPTION

F60UP60DN using the lastest FRED FAB process(planar passivation chip) with ultrafast and soft recovery characteristic.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	V _{RRM}		600	V
Continuous forward current	I _{F(AV)}	T _c =110°C	60	A
Single pulse forward current	I _{FSM}	T _c =25°C	480	
Maximum repetitive forward current	I _{FRM}	Square wave, 20kHz	120	
Operating junction	T _j		175	°C
Storage temperatures	T _{stg}		-55 to +175	°C

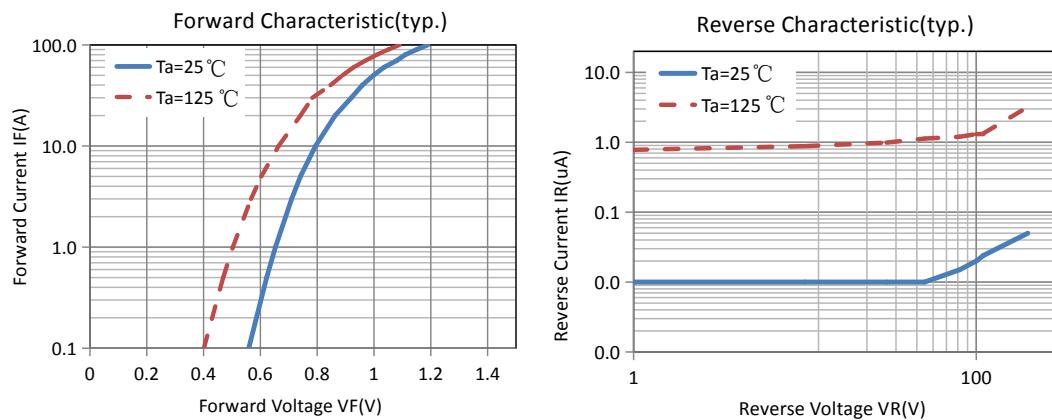
Electrical characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Units
Breakdown voltage Blocking voltage	V _{BR} , V _R	I _R =100μA	600			V
Forward voltage (Per Diode)	V _F	I _F =30A		1.30	1.60	V
		I _F =30A, T _j =125°C		1.05	1.40	
Reverse leakage current(Per Diode)	I _R	V _R = V _{RRM}			20	μA
		T _j =150°C, V _R =600V			200	
Reverse recovery time(Per Diode)	t _{rr}	I _F =0.5A, I _R =1A, I _{RR} =0.25A		35	45	ns
		I _F =1A, V _R =30V, di/dt =200A/us		28	35	

Thermal characteristics

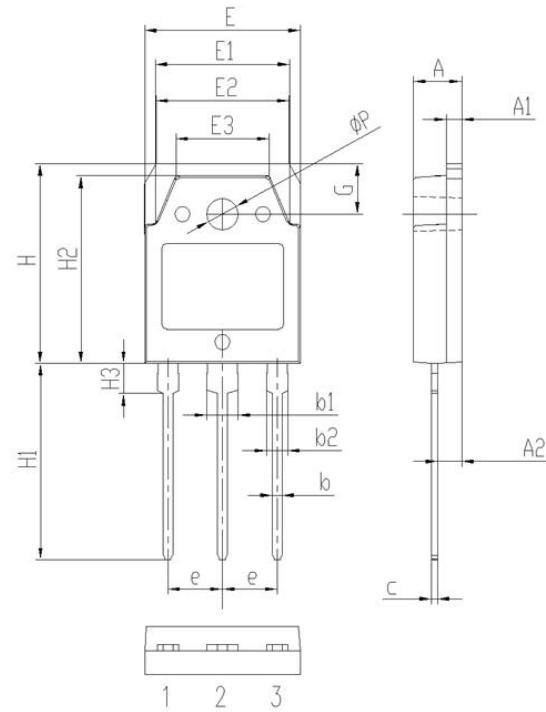
Paramter	Symbol	Typ	Units
Junction-to-Case	R _{θJC}	0.8	°C/W

Electrical performance (typical)



Package Information

TO-3PB PACKAGE



Symbol	Dimensions(millimeters)	
	Min.	Max.
A	4.60	5.00
A1	1.30	1.70
A2	2.20	2.60
b	0.80	1.20
b1	2.90	3.30
b2	1.90	2.30
c	0.40	0.80
e	5.25	5.65
E	15.3	15.7
E1	13.2	13.6
E2	13.1	13.5
E3	9.10	9.50
H	19.7	20.1
H1	19.1	20.1
H2	18.3	18.7
H3	2.80	3.20
G	4.80	5.20
ΦP	3.00	3.40